KEMET Part Number: T502D685M035AG6310



T502, Tantalum, MnO2 Tantalum, High Temperature, 6.8 uF, 20%, 35 VDC, SMD, MnO2, Un-Encapsulated, High Temperature, 230C, N/A, 1.8 Ohms, 7343, Height Max = 3.1mm



Dimensions		
Footprint	7343	
L	7.3mm +/-0.3mm	
W	4.3mm +/-0.3mm	
Н	2.8mm +/-0.3mm	
Т	0.13mm REF	
S	1.3mm +/-0.3mm	
F	2.4mm +/-0.1mm	
Α	3.6mm MIN	
В	0.5mm +/-0.15mm	
Р	0.9mm REF	
R	1mm REF	
Х	0.1mm +/-0.1mm	

Packaging Specifications		
Packaging:	T&R, 178mm	
Packaging Quantity:	500	

General Information		
Supplier:	KEMET	
Series:	T502	
Dielectric:	MnO2 Tantalum	
Style:	SMD Chip	
Description:	SMD, MnO2, Un-Encapsulated, High Temperature, 230C	
Features:	230C	
RoHS:	Yes	
Termination:	Gold	
Notes:	In Polarity Stripe, At KEMET's Option, Type May Be Indicated: No Symbol = Standard (Or Low Leakage) MnO2 Tantalum Chip, O = LowESR T494, R = Low ESR T495, F = Fused T496, HT = 150C Rated T498 (or B45196P, B45198P), H = 175C rated T499, M = Multiple Anode	
Shelf Life:	156 Weeks	
MSL:	1	

Specifications		
Capacitance:	6.8 uF	
Capacitance Tolerance:	20%	
Voltage DC:	35 VDC (85C), 28.7 VDC (125C), 11.6 VDC (230C)	
Temperature Range:	-55/+230C	
Rated Temperature:	85C	
Dissipation Factor:	6.00% 120Hz 25C	
Failure Rate:	N/A	
Resistance:	1.8 Ohms (100kHz 25C)	
Ripple Current:	289 mA (100kHz 45C)	
Leakage Current:	2.4 uA (5min 25C)	

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